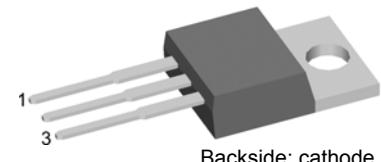
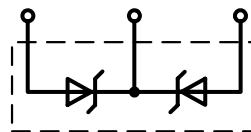


Schottky

High Performance Schottky Diode
Low Loss and Soft Recovery
Common Cathode

 $V_{RRM} = 150\text{ V}$ **$I_{FAV} = 2 \times 15\text{ A}$** **$V_F = 0.75\text{ V}$** **Part number****DSA 30 C 150PB****Features / Advantages:**

- Very low V_F
- Extremely low switching losses
- Low I_{rm} -values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching
- Low losses

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package:

TO-220AB

- Industry standard outline
- Epoxy meets UL 94V-0
- RoHS compliant

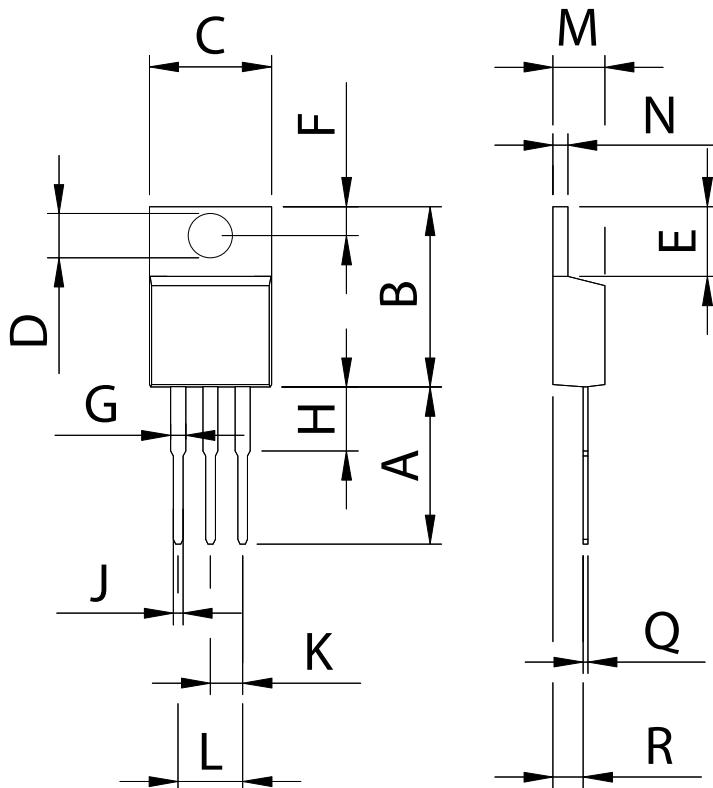
Ratings					
Symbol	Definition	Conditions	min.	typ.	max.
V_{RRM}	max. repetitive reverse voltage	$T_{VJ} = 25\text{ }^\circ\text{C}$			150
I_R	reverse current	$V_R = 150\text{ V}$			0.5
		$V_R = 150\text{ V}$			2.5
V_F	forward voltage	$I_F = 15\text{ A}$			0.89
		$I_F = 30\text{ A}$			1.02
		$I_F = 15\text{ A}$			0.75
		$I_F = 30\text{ A}$			0.89
I_{FAV}	average forward current	rectangular, $d = 0.5$	$T_c = 150\text{ }^\circ\text{C}$		15
V_{FO} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175\text{ }^\circ\text{C}$		0.55
					8.8
R_{thJC}	thermal resistance junction to case				1.75
T_{VJ}	virtual junction temperature		-55		175
P_{tot}	total power dissipation				85
I_{FSM}	max. forward surge current	$t_p = 10\text{ ms (50 Hz), sine}$	$T_{VJ} = 45\text{ }^\circ\text{C}$		120
C_J	junction capacitance	$V_R = \text{tbd V}; f = 1\text{ MHz}$	$T_{VJ} = 25\text{ }^\circ\text{C}$	tbd	pF
E_{AS}	non-repetitive avalanche energy	$I_{AS} = 1\text{ A}; L = 100\text{ }\mu\text{H}$	$T_{VJ} = 25\text{ }^\circ\text{C}$		0.05
I_{AR}	repetitive avalanche current	$V_A = 1.5 \cdot V_R$ typ.; $f = 10\text{ kHz}$			0.1

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
I_{RMS}	RMS current	per pin*			35	A
R_{thCH}	thermal resistance case to heatsink			0.50		K/W
M_D	mounting torque		0.4		0.6	Nm
F_C	mounting force with clip		20		60	N
T_{stg}	storage temperature		-55		150	°C
Weight				2		g

* I_{RMS} is typically limited by: 1. pin-to-chip resistance; or by 2. current capability of the chip.

In case of 1, a common cathode/anode configuration and a non-isolated backside, the whole current capability can be used by connecting the backside.

Outlines TO-220AB



Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	12.70	13.97	0.500	0.550
B	14.73	16.00	0.580	0.630
C	9.91	10.66	0.390	0.420
D	3.54	4.08	0.139	0.161
E	5.85	6.85	0.230	0.270
F	2.54	3.18	0.100	0.125
G	1.15	1.65	0.045	0.065
H	2.79	5.84	0.110	0.230
J	0.64	1.01	0.025	0.040
K	2.54	BSC	0.100	BSC
M	4.32	4.82	0.170	0.190
N	1.14	1.39	0.045	0.055
Q	0.35	0.56	0.014	0.022
R	2.29	2.79	0.090	0.110